ENHANCED REMOTE PLASMA CLEANING

ABSTRACT OF THE DISCLOSURE

Methods and apparatus for cleaning semiconductor processing equipment.

The apparatus include both local and remote gas dissociators coupled to a semiconductor

processing chamber to be cleaned. The methods include introducing a precursor gas into the remote dissociator where the gas is dissociated and introducing a portion of the dissociated gas into the chamber. Another portion of the dissociated gas which re-associates before introduction into the chamber is also introduced into the chamber where it is again dissociated. The dissociated gas combines with contaminants in the chamber and is exhausted from the chamber along with the contaminants.

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